



AUTOMOTIVE COMPLIANT DUAL AND QUAD OPERATIONAL AMPLIFIERS

Description

The LM2902Q/LM2902AQ/LM2904Q/LM2904AQ series consist of two or four independent high-gain operational amplifiers with very low input offset voltage specification. They are designed to operate from a single power supply over a wide range of voltages; however, operation from split power supplies is also possible. They offer low power supply current independent of the magnitude of the power supply voltage.

The LM2904Q/LM2904AQ dual devices are available in SO-8, TSSOP-8 and MSOP-8 packages; the LM2902Q/LM2902AQ quad devices are available in SO-14 and TSSOP-14 packages. All of them are in industry-standard pin outs, and use "green" mold compound as standard.

The LM2902Q/LM2902AQ/LM2904Q/LM2904AQ are characterized for operation from -40°C to +125°C, qualified to AEC-Q100 Grade 1 and are automotive compliant, supporting PPAPs.

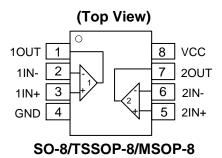
Features

- Wide Power Supply Voltage Range
 - Single Supply: 3V to 36V
 - Dual Supplies: ±1.5V to ±18V
- Very Low Supply Current Drain Independent of Supply Voltage
 - LM2904Q: 500µA
 - LM2902Q: 700µA
- Low Input Bias Current: 20nA
- Low Input Offset Voltage
 - A Versions: 1mV (typ)
 - Non-A Version: 2mV (typ)
- Large DC Voltage Gain: 100dB
- Wide Bandwidth (Unity Gain): 700kHz (Temperature Compensated)
- Internally Compensated with Unity Gain
- Input Common-Mode Voltage Range Includes Ground
- Differential Input Voltage Range Equal to Power Supply Voltage
- Large Output Voltage Swing: 0V to V_{CC} -1.5V
- Qualified to AEC-Q100 Grade 1
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The LM2902Q/LM2902AQ/LM2904Q/LM2904AQ is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

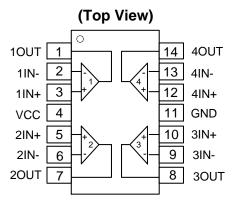
https://www.diodes.com/quality/product-definitions/

Pin Assignments

LM2904Q/LM2904AQ



LM2902Q/LM2902AQ

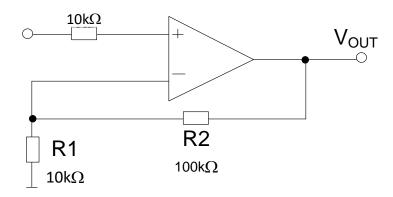


SO-14/TSSOP-14

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit

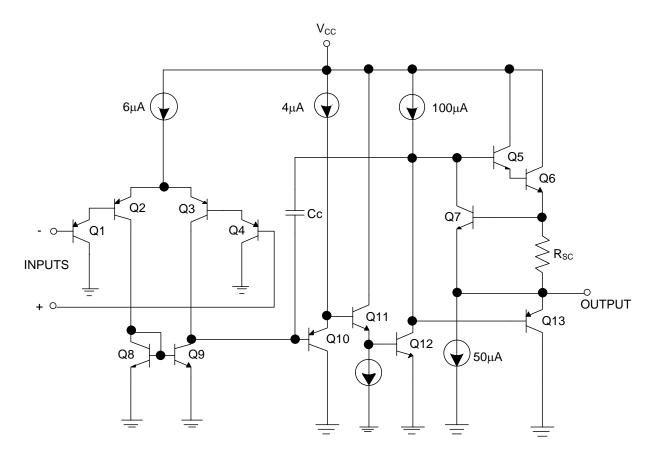


Pin Descriptions

Pin Number	Pin Name	Function
LM2902Q/LM2902AQ		
1	10UT	Channel 1 Output
2	1IN-	Channel 1 Inverting Input
3	1IN+	Channel 1 Non-Inverting Input
4	VCC	Chip Supply Voltage
5	2IN+	Channel 2 Non-Inverting Input
6	2IN-	Channel 2 Inverting Input
7	2OUT	Channel 2 Output
8	3OUT	Channel 3 Output
9	3IN-	Channel 3 Inverting Input
10	3IN+	Channel 3 Non-Inverting Input
11	GND	Ground
12	4IN+	Channel 4 Non-Inverting Input
13	4IN-	Channel 4 Inverting Input
14	4OUT	Channel 4 Output
LM2904Q/LM2904AQ		
1	1OUT	Channel 1 Output
2	1IN-	Channel 1 Inverting Input
3	1IN+	Channel 1 Non-Inverting Input
4	GND	Ground
5	2IN+	Channel 2 Non-Inverting Input
6	2IN-	Channel 2 Inverting Input
7	2OUT	Channel 2 Output
8	VCC	Chip Supply Voltage



Functional Block Diagram



Functional Block Diagram of LM2902Q/LM2902AQ/LM2904Q/LM2904AQ (Each Amplifier)



Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter		Rating	Unit
Vcc	Supply Voltage		±18 or 36	V
V _{ID}	Differential Input Voltage		36	V
VIN	Input Voltage		-0.3 to +36	V
	θ _{JA} Package Thermal Impedance (Note 5)	SO-8	150	
		TSSOP-8	175	
θJA		Package Thermal Impedance (Note 5)	MSOP-8	200
		SO-14	89	
		TSSOP-14	100	
	Output Short-Circuit to GND (One Amplifier) (Note 6)	V _{CC} ≤ 15V and T _A = +25°C	Continuous	_
T _A	Operating Temperature Range		-40 to +125	°C
TJ	Operating Junction Temperature		+150	°C
Tstg	Storage Temperature Range	Storage Temperature Range		°C

Notes:

- 4. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.
- 5. Maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(MAX)} T_A) / \theta_{JA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.
- 6. Short circuits from outputs to V_{CC} or ground can cause excessive heating and eventual destruction.

ESD Ratings

Parameter	Rating	Unit	
	SO-14	500	
	TSSOP-14	500	
Human Body Mode ESD Protection (Note 7)	SO-8	500	
	TSSOP-8	500	
	MSOP-8	< 500	V
	SO-14		V
	TSSOP-14		
Charge Device Mode ESD Protection	SO-8	1,000	
	TSSOP-8		
	MSOP-8		

Note:

7. Human body model, $1.5k\Omega$ in series with 100pF.

Recommended Operating Conditions (Over Operating Free-Air Temperature Range, unless otherwise noted.)

Parameter	Min	Max	Unit		
Cumply Voltage	Single Supply	2	36	V	
Supply Voltage	Dual Supply	±1	±18	V	
Ambient Temperature Range	-40	+125	°C		
Junction Temperature Range	-40	+125	C		



Electrical Characteristics (Notes 8 and 9) (@ Vcc = +5.0V, TA = +25°C, unless otherwise specified.)

LM2902Q/LM2902AQ

Symbol	Paramet	er	Con	dition	s	TA	Min	Тур	Max	Unit
			V V Ninima	N 4.5	T _A = +25°C	_	2	7		
			VIC = VCMR Minimu Vo = 1.4V	um	Non-A Device	Full Range	_	_	10	\/
V _{IO}	Input Offset Voltage		Vcc = 5V to Maxim	num	A-Suffix	T _A = +25°C	_	1	2	mV
			$Rs = 0\Omega$		Device	Full Range	_	_	4	
ΔV10/ΔΤ	Input Offset Voltage Drift	Temperature	$Rs = 0\Omega$			Full Range	_	7	_	μV/°C
	January Diag Comment		I _{IN+} or I _{IN} - with OU	IT in Li	near Range	T _A = +25°C	_	-20	-200	^
lв	Input Bias Current		V _{CMR} = 0V (Note 1	10)	•	Full Range	_	_	-500	nA
La	Input Offset Current		lu	,		T _A = +25°C	_	2	50	nΛ
lιο	Input Offset Current		I_{IN+} - I_{IN-} , $V_{CM} = 0$	V		Full Range	_	_	150	nA
ΔΙιο/ΔΤ	Input Offset Current Drift	Temperature	_			Full Range	_	10	_	pA/°C
V _{CMR}	Input Common-Mode	Voltage	V _{CC} = 30V (Note 11)		T _A = +25°C	0 to V _{CC} -1.5	_	_	- V	
VCMR	Range				Full Range	0 to Vcc -2.0	_	_		
laa	Supply Current		$V_O = 0.5 V_{CC}$, No L	Load	$V_{CC} = 30V$	Full Range	_	1.0	3.0	mA
Icc	(Four Amplifiers)		Vo = 0.5 Vcc, No L	_oad	Vcc = 5V	Full Range	1	0.7	1.2	IIIA
Δ	Valtage Coin		$V_{CC} = 15V$, $V_{OUT} = 1V$ to $11V$ $R_L \ge 2k\Omega$		T _A = +25°C	25	100	_	V/mV	
Av	Voltage Gain				Full Range	15	_		V/IIIV	
CMRR	Common Mode Reje	ction Ratio	DC, $V_{CMR} = 0V$ to V_{CC} -1.5V		T _A = +25°C	60	70	_	dB	
PSRR	Power Supply Reject	ion Ratio	Vcc = 5V to 30V			T _A = +25°C	70	100		dB
-	Amplifier to Amplifier	Coupling	f = 1kHz to 20kHz (Input Referred) (Note 12)			T _A = +25°C	_	-120	_	dB
			$V_{IN-} = 1V, V_{IN+} = 0V$ $V_{O} = 200 \text{mV}$	V, Vcc	= 15V	T _A = +25°C	12	50		μA
Isink		Sink	V _{IN-} = 1V, V _{IN+} = 0	V, Vcc	C= 15V TA = +25		10	20	_	
	Output Current		Vo = 15V			Full Range	5	_		
		Source	V _{IN+} = 1V, V _{IN-} = 0V, V _{CC} = 15V V _O = 0V		= 15V	T _A = +25°C	-20	-40	-60	mA
ISOURCE		Source				Full Range	-10	_	_]
Isc	Short-Circuit to Ground Vcc = 5		Vcc = 5V, GND = -	cc = 5V, GND = -5V, Vo = 0V		T _A = +25°C	_	±40	±60	mA
			$R_L = 10k\Omega$		T _A = +25°C	_	V _{CC} -1.5			
Vон	High-Level Output Vo	oltage Swing	$V_{CC} = 30V$ $R_{L} = 2k\Omega$ $R_{L} \ge 10k\Omega$		Ω	Full Range	26		_	V
					. un realige	27	28			
VoL	Low-Level Output Vo	Itage Swing	R _L ≤ 10kΩ			Full Range	_	5	20	mV

^{8.} Typical values are all at $T_A = +25$ °C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

^{9.} All limits are guaranteed by testing or statistical analysis. Limits over the full temperature (-40 ≤ T_A ≤ +125°C) are guaranteed by design, but not tested in

^{10.} The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so that no loading change exists on the input lines.

^{11.} The input common-mode voltage of either input signal voltage should not be allowed to become negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V_{CC} -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of

^{12.} Due to proximity of external components, ensure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.



Electrical Characteristics (continued) (Notes 8 and 9) (@ Vcc = +5.0V, TA = +25°C, unless otherwise specified.)

LM2904Q/LM2904AQ

Symbol	Parai	neter	Con	ditions		TA	Min	Тур	Max	Unit
			V _{IC} = V _{CMR} Minimu	ım N	Non-A Device	T _A = +25°C	_	2	7	
V _{IO}	Input Offset Volta	age	Vic = VCMR Millimu Vo = 1.4V	IIII I'	Non-A Device	Full Range	_		10	mV
VIO	input Onset voite	ige	Vcc = 5V to Maxim	ium A	A-Suffix	T _A = +25°C	_	1	2	IIIV
			$Rs = 0\Omega$		Device	Full Range	_		4	
ΔV10/ΔΤ	Input Offset Volta Drift	age Temperature	$R_S = 0\Omega$			Full Range	_	7	_	μV/°C
1-	Innut Ding Currer		I _{IN+} or I _{IN} - with OU	T in Line	ear Range	T _A = +25°C	_	-20	-250	πΛ
lв	Input Bias Currer	ıt	VCMR = 0V (Note 1	0)		Full Range	_	_	-500	nA
lia	Input Offset Curre	ont	l l Va 0V	,		T _A = +25°C	_	2	50	nA
l _{IO}	Input Onset Curr	ent	I_{IN+} - I_{IN-} , $V_{CM} = 0V$	1		Full Range	_	-	150	IIA
ΔΙιο/ΔΤ	Input Offset Curro Drift	ent Temperature	_			Full Range		10	_	pA/°C
V2.15	Input Common-M	lode Voltage			T _A = +25°C	0 to V _{CC} -1.5	1	_	V	
V _{CMR}	Range		V _{CC} = 30V (Note 11)		Full Range	0 to Vcc -2.0		_	V	
Icc	Supply Current		$V_O = 0.5 V_{CC}$, No L	oad	V _{CC} = 30V	Full Range	_	0.7	2.0	mA
icc	(Two Amplifiers)		Vo = 0.5 Vcc, No L	oad	Vcc = 5V	Full Range	_	0.5	1.2	117.
Av	Voltage Gain		$V_{CC} = 15V$, $V_{OUT} = 1V$ to $11V$ $R_L \ge 2k\Omega$		T _A = +25°C	25	100	_	V/mV	
Av	voltage Calif				Full Range	15	_	_		
CMRR	Common Mode F	Rejection Ratio	DC, V _{CMR} = 0V to \	Vcc-1.5	V	$T_A = +25$ °C	60	70	_	dB
PSRR	Power Supply Re	ejection Ratio	Vcc = 5V to 30V			T _A = +25°C	70	100	_	dB
_	Amplifier to Ampl	ifier Coupling	f = 1kHz to $20kHz$ (`	,	T _A = +25°C	_	120	_	dB
			$V_{IN-} = 1V, V_{IN+} = 0V$ $V_O = 200mV$	/, V _{CC} =	15V	T _A = +25°C	12	50	_	μA
Isink		Sink	V _{IN-} = 1V, V _{IN+} = 0V	/, Vcc=	15V	T _A = +25°C	10	20	_	
	Output Current		$V_0 = 15V$			Full Range	5		_	mA
Isource		Source	V _{IN+} = 1V, V _{IN-} = 0V, V _{CC} = 15V V _O = 0V		15V	T _A = +25°C	-20	-40	-60	IIIA
ISOURCE		Source			Full Range	-10		_		
I _{SC}	Sc Short-Circuit to Ground		V _{CC} = 5V, GND = -5V, V _O = 0V		$T_A = +25$ °C	_	±40	±60	mA	
			$R_L = 10k\Omega$		T _A = +25°C	V _{CC} -1.5	_	_		
Vон	High-Level Outpu	ut Voltage Swing	\/cc = 30\/	$R_L = 2k\Omega$		Full Range	26	_	_	V
			$V_{CC} = 30V$ $R_L \ge 10k\Omega$		- un realige	27	28	_		
Vol	Low-Level Outpu	t Voltage Swing	R _L ≤ 10kΩ			Full Range		5	20	mV

^{8.} Typical values are all at $T_A = +25$ °C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not quaranteed on shipped production material.

^{9.} All limits are guaranteed by testing or statistical analysis. Limits over the full temperature (-40 ≤ T_A ≤ +125°C) are guaranteed by design, but not tested in production.

^{10.} The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so that no loading change exists on the input lines.

^{11.} The input common-mode voltage of either input signal voltage should not be allowed to become negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V_{CC} -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of

^{12.} Due to proximity of external components, ensure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.



AC Electrical Characteristics (Notes 8 and 9) (@ Vcc = ±15.0V, TA = +25°C, unless otherwise specified.)

LM2902Q/LM2902AQ

Symbol	Parameter	Conditions	Тур	Unit
SR	Slew Rate at Unity Gain	$R_L = 1M\Omega$, $C_L = 30pF$, $V_I = \pm 10V$	0.3	V/µs
B1	Unity Gain Bandwidth	$R_L = 1M\Omega$, $C_L = 20pF$	0.7	MHz
Vn	Equivalent Input Noise Voltage	$R_S = 100\Omega$, $V_I = 0V$, $f = 1kHz$	40	nV/√Hz

LM2904Q/LM2904AQ

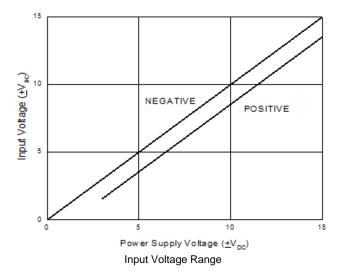
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SR	Slew Rate at Unity Gain	$R_L = 1M\Omega$, $C_L = 30pF$, $V_I = \pm 10V$	0.3	V/µs
B1	Unity Gain Bandwidth	$R_L = 1M\Omega$, $C_L = 20pF$	0.7	MHz
Vn	Equivalent Input Noise Voltage	$R_S = 100\Omega$, $V_I = 0V$, $f = 1kHz$	40	nV/√Hz

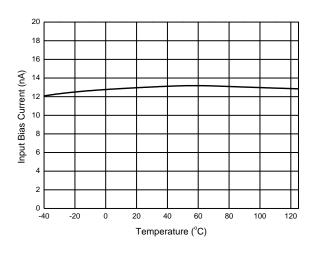
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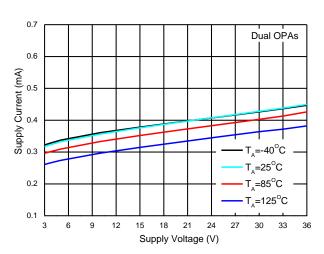
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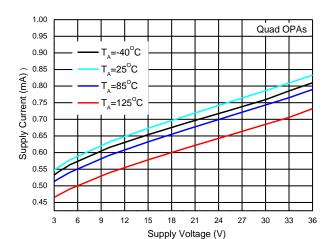


Performance Characteristics





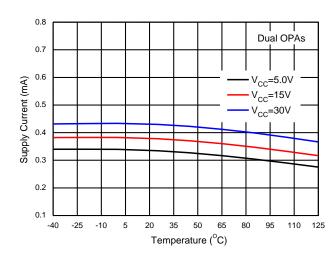


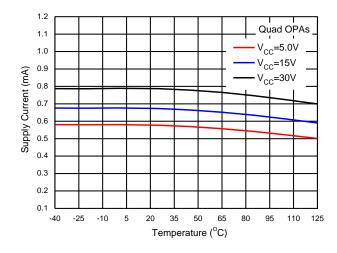


Input Current

Supply Current vs. Supply Voltage (LM2904Q/LM2904AQ)

Supply Current vs. Supply Voltage (LM2902Q/LM2902AQ)



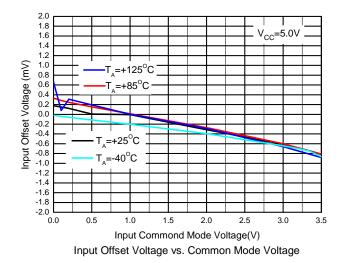


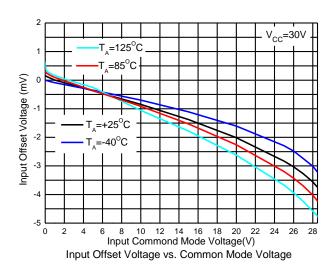
Supply Current vs. Temperature (LM2904Q/LM2904AQ)

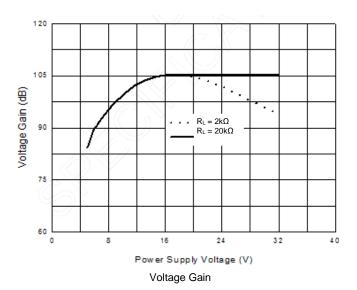
Supply Current vs. Temperature (LM2902Q/LM2902AQ)

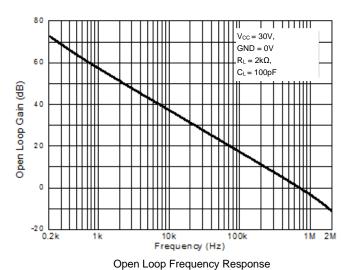


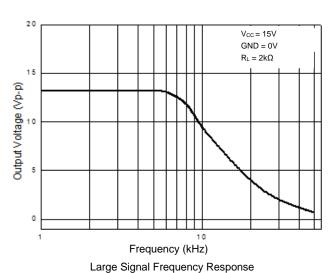
Performance Characteristics (continued)

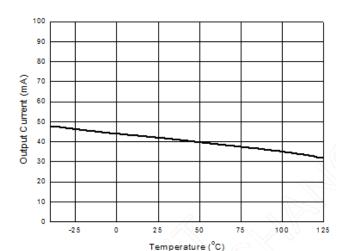








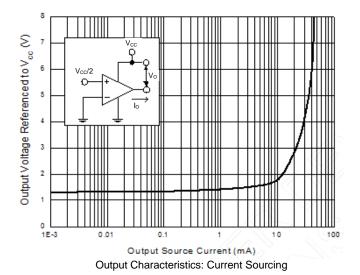


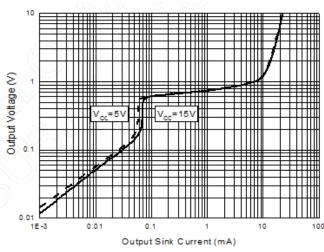


Current Limit

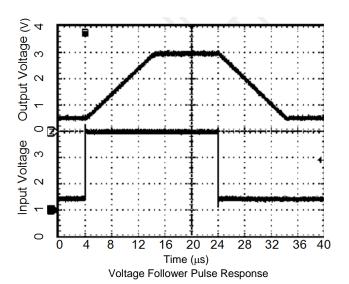


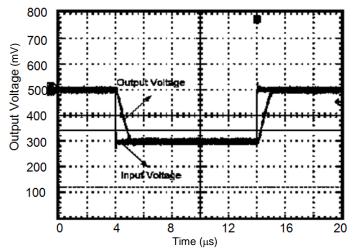
Performance Characteristics (continued)





Output Characteristics: Current Sinking





Voltage Follower Pulse Response (Small Signal)



Application Information

General Information

The LM2902Q/LM2904AQ/LM2904AQ series op amps which operate with only a single power supply voltage, have true-differential inputs and remain in the linear mode with an input common-mode voltage of 0V. These amplifiers operate over a wide range of power supply voltage with little change in performance characteristics. At +25°C, amplifier operation is possible down to a minimum supply voltage of 2.3V.

Precautions should be taken to ensure that the power supply for the integrated circuit never becomes reversed in polarity, or that the unit is not inadvertently installed backwards in a test socket. If precaution is not taken, an unlimited current surge through the resulting forward diode within the IC may occur and could cause fusing of the internal conductors, destroying the unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V+ without damaging the device. Protection should be provided to prevent the input voltages from becoming negative more than -0.3V (@ +25°C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply current drain, the amplifiers have a class A output stage for small signal levels which converts to class B in a large signal mode. This allows the amplifiers to achieve both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For AC applications where the load is capacitive coupled to the output of the amplifier, a resistor should be used from the output of the amplifier to ground to increase the class A bias current, and prevent crossover distortion. Where the load is directly coupled, as in DC applications, there is no crossover distortion.

Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50pF can be accommodated using the worst-case non-inverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

The bias network of the LM2902Q/LM2902AQ/LM2904AQ series establishes a quiescent current which is independent of the magnitude of the power supply voltage over the range of 3V to 30V.

Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short-circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive function temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of output source current which is available at +25°C provides a larger output current capability at elevated temperatures (see *Typical Performance Characteristics*) than a standard IC op amp.

The circuits presented in *Typical Applications Circuit* section emphasize operation on a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of Vcc/2) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.



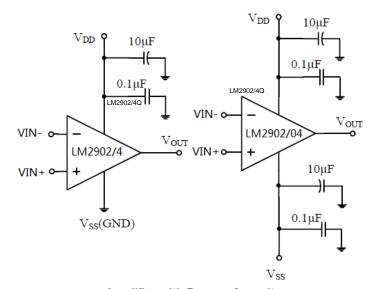
Application Information (continued)

Power Supply Bypassing and Layout

The LM2902Q/LM2904Q/LM2904Q/LM2904AQ family operates from both single supply voltage ranging 3V to 36V, or dual supply voltage ±1.5V to ±18V.

As with any operation amplifier, proper supply bypassing is critical for low-noise performance and high power supply rejection. For single-supply operation system, a minimum 0.1µF bypass capacitor should be recommended to place as close as possible between Vcc pin and GND. For dual-supply operation, both the positive supply pin and negative supply pin should be bypassed to ground with a separate 0.1µF ceramic capacitor.

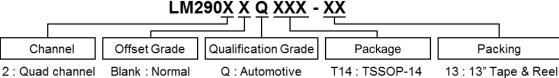
2.2µF tantalum capacitor can be added for better performance. Keep the length of leads and traces that connect capacitors between LM2902Q/LM2902AQ/LM2904AQ power supply pin and ground as short as possible.



Amplifier with Bypass Capacitors



Ordering Information



4 : Dual channel $A:Low V_{IO}$ Q: Automotive T14: TSSOP-14

S14: SO-14 S:SO-8 TH: TSSOP-8

M8: MSOP-8

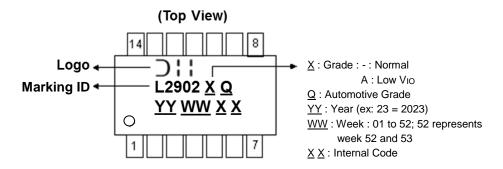
Part Number	Part Number Suffix	Dookses Code	Dockogo (Noto 42)	Pac	king
Part Number	Part Number Sumx	Package Code	Package (Note 13)	Qty.	Carrier
LM2902QT14-13	-13	T14	TSSOP-14	2,500	Tape & Reel
LM2902AQT14-13	-13	T14	TSSOP-14	2,500	Tape & Reel
LM2902QS14-13	-13	S14	SO-14	2,500	Tape & Reel
LM2902AQS14-13	-13	S14	SO-14	2,500	Tape & Reel
LM2904QS-13	-13	S	SO-8	2,500	Tape & Reel
LM2904AQS-13	-13	S	SO-8	2,500	Tape & Reel
LM2904QTH-13	-13	TH	TSSOP-8	2,500	Tape & Reel
LM2904AQTH-13	-13	TH	TSSOP-8	2,500	Tape & Reel
LM2904QM8-13	-13	M8	MSOP-8	2,500	Tape & Reel
LM2904AQM8-13	-13	M8	MSOP-8	2,500	Tape & Reel

13. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

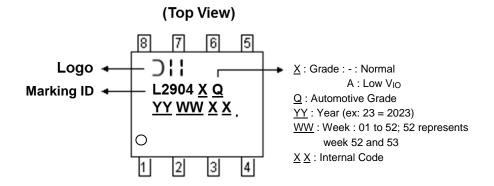


Marking Information

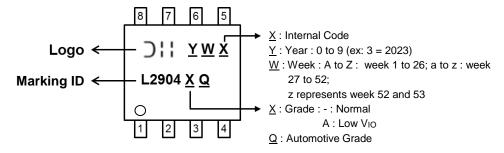
(1) TSSOP-14 and SO-14



(2) SO-8



(3) MSOP-8 and TSSOP-8

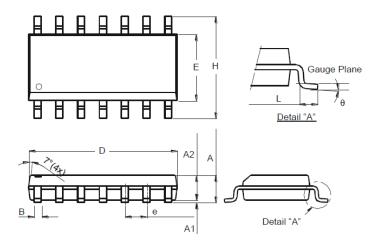




Package Outline Dimensions

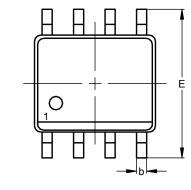
Please see http://www.diodes.com/package-outlines.html for the latest version.

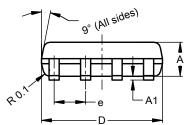
SO-14

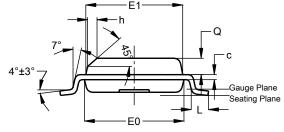


	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45	Тур			
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
Н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Dimensions in mm					

SO-8







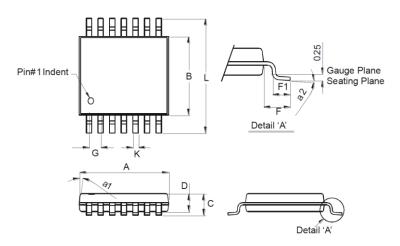
	S	D-8	
Dim	Min	Max	Тур
Α	1.40	1.50	1.45
A1	0.10	0.20	0.15
þ	0.30	0.50	0.40
C	0.15	0.25	0.20
D	4.85	4.95	4.90
Е	5.90	6.10	6.00
E1	3.80	3.90	3.85
E0	3.85	3.95	3.90
е			1.27
h			0.35
٦	0.62	0.82	0.72
Ø	0.60	0.70	0.65
All	Dimens	ions in	mm



Package Outline Dimensions (continued)

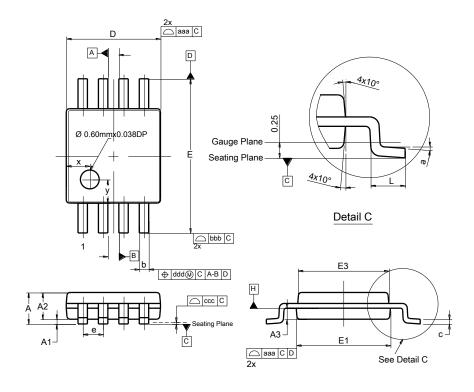
Please see http://www.diodes.com/package-outlines.html for the latest version.

TSSOP-14



	TSSOP-1	4		
Dim	Min	Max		
a1	7° (4X)		
a2	0°	8°		
Α	4.9	5.10		
В	4.30	4.50		
С	-	1.2		
D	0.8	1.05		
F	1.00	Тур		
F1	0.45	0.75		
G	0.65	Тур		
K	0.19	0.30		
L 6.40 Typ				
All Dir	nension	s in mm		

MSOP-8



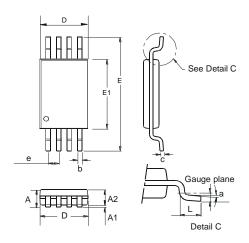
MSOP-8			
Dim	Min	Max	Тур
Α		1.10	
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
А3	0.29	0.49	0.39
b	0.22	0.38	0.30
С	0.08	0.23	0.15
D	2.90	3.10	3.00
Е	4.70	5.10	4.90
E1	2.90	3.10	3.00
E3	2.85	3.05	2.95
е			0.65
L	0.40	0.80	0.60
а	0°	8°	4°
X	-		0.750
у	1	-	0.750
aaa	0.20		
bbb	0.25		
CCC	0.10		
ddd	0.13		
All Dimensions in mm			



Package Outline Dimensions (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSSOP-8



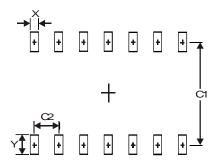
	TSSOP-8		
Dim	Min	Max	Тур
а	0.09	_	_
Α	_	1.20	_
A 1	0.05	0.15	_
A2	0.825	1.025	0.925
b	0.19	0.30	_
С	0.09	0.20	_
D	2.90	3.10	3.025
е	_	ı	0.65
E	_	_	6.40
E1	4.30	4.50	4.425
L	0.45	0.75	0.60
All Dimensions in mm			



Suggested Pad Layout

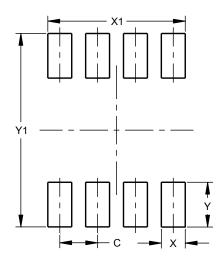
Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-14



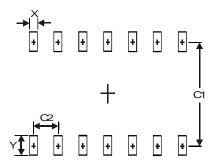
Dimensions	Value (in mm)
X	0.60
Υ	1.50
C1	5.4
C2	1.27

SO-8



Dimensions	Value (in mm)
C	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

TSSOP-14



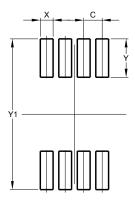
Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



Suggested Pad Layout (continued)

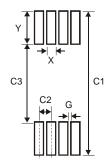
Please see http://www.diodes.com/package-outlines.html for the latest version.

MSOP-8



Dimensions	Value (in mm)
С	0.650
Х	0.450
Y	1.350
Y1	5.300

TSSOP-8



Dimensions	Value (in mm)
Х	0.45
Υ	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20

Mechanical Data

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: SO-8 0.074 grams (Approximate)

SO-14 – 0.14 grams (Approximate)

TSSOP-8 – 0.041 grams (Approximate)

MSOP-8 – 0.027 grams (Approximate)

TSSOP-14 – 0.052 grams (Approximate)



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